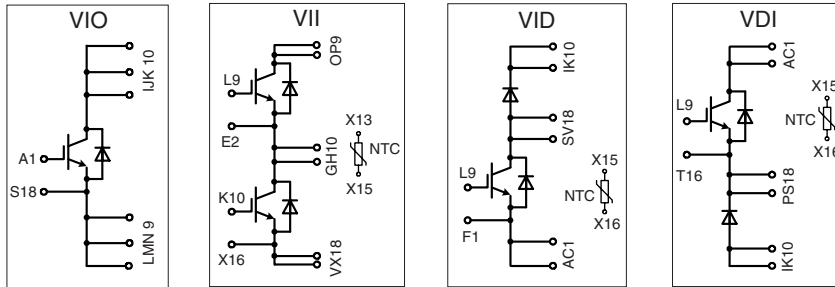


IGBT Modules in ECO-PAC 2

Short Circuit SOA Capability
Square RBSOA

$I_{C25} = 49 \text{ A}$
 $V_{CES} = 1200 \text{ V}$
 $V_{CE(sat) \text{ typ.}} = 3.1 \text{ V}$



Pin arrangement see outlines

IGBTs

Symbol	Conditions	Maximum Ratings
V_{CES}	$T_{VJ} = 25^\circ\text{C to } 150^\circ\text{C}$	1200 V
V_{GES}		± 20 V
I_{C25}	$T_C = 25^\circ\text{C}$	49 A
I_{C80}	$T_C = 80^\circ\text{C}$	33 A
I_{CM} V_{CEK}	$V_{GE} = \pm 15 \text{ V}; R_G = 47 \Omega; T_{VJ} = 125^\circ\text{C}$ RBSOA, Clamped inductive load; $L = 100 \mu\text{H}$	50 A V_{CES}
t_{SC} (SCSOA)	$V_{CE} = V_{CES}; V_{GE} = \pm 15 \text{ V}; R_G = 47 \Omega; T_{VJ} = 125^\circ\text{C}$ non-repetitive	10 μs
P_{tot}	$T_C = 25^\circ\text{C}$	208 W

Symbol	Conditions	Characteristic Values ($T_{VJ} = 25^\circ\text{C}$, unless otherwise specified)			
		min.	typ.	max.	
$V_{CE(sat)}$	$I_C = 50 \text{ A}; V_{GE} = 15 \text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		3.1 3.5	3.7 V V	
$V_{GE(th)}$	$I_C = 1 \text{ mA}; V_{GE} = V_{CE}$	4.5		6.5 V	
I_{CES}	$V_{CE} = V_{CES}; V_{GE} = 0 \text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$			1.1 mA 4.2 mA	
I_{GES}	$V_{CE} = 0 \text{ V}; V_{GE} = \pm 20 \text{ V}$			180 nA	
$t_{d(on)}$ t_r $t_{d(off)}$ t_f E_{on} E_{off}	Inductive load, $T_{VJ} = 125^\circ\text{C}$ $V_{CE} = 600 \text{ V}; I_C = 30 \text{ A}$ $V_{GE} = 15/0 \text{ V}; R_G = 47 \Omega$		100 70 500 70 4.6 3.4	ns ns ns ns mJ mJ	
C_{ies}		$V_{CE} = 25 \text{ V}; V_{GE} = 0 \text{ V}; f = 1 \text{ MHz}$	1.65		nF
R_{thJC} R_{thJH}		(per IGBT) with heatsink compound (0.42 K/m.K; 50 μm)	1.2		0.6 K/W K/W

Features

- NPT IGBT's
 - positive temperature coefficient of saturation voltage
 - fast switching
- FRED diodes
 - fast reverse recovery
 - low forward voltage
- Industry Standard Package
 - solderable pins for PCB mounting
 - isolated DCB ceramic base plate

Advantages

- space and weight savings
- reduced protection circuits
- leads with expansion bend for stress relief

Typical Applications

- AC and DC motor control
- AC servo and robot drives
- power supplies
- welding inverters

**Recommended replacement:
Please contact your local
sales office**

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Reverse diodes (FRED)

Symbol	Conditions	Maximum Ratings
I_{F25}	$T_C = 25^\circ\text{C}$	49 A
I_{F80}	$T_C = 80^\circ\text{C}$	31 A

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.

V_F	$I_F = 30\text{ A}; T_{VJ} = 25^\circ\text{C}$		2.4	2.7
			1.77	

I_{RM} t_{rr}	$I_F = 30\text{ A}; di_F/dt = 500\text{ A}/\mu\text{s}; T_{VJ} = 125^\circ\text{C}$ $V_R = 600\text{ V}; V_{GE} = 0\text{ V}$		27	A
			150	ns

R_{thJC} R_{thJH}	with heatsink compound (0.42 K/m.K; 50 μm)	2.6	1.3	K/W K/W
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Temperature Sensor NTC

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.

R_{25} $B_{25/50}$	$T = 25^\circ\text{C}$	4.75	5.0	5.25
			3375	k Ω K

Module

Symbol	Conditions	Maximum Ratings
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T_{VJ} T_{stg}		-40...+150 -40...+150	$^\circ\text{C}$ $^\circ\text{C}$
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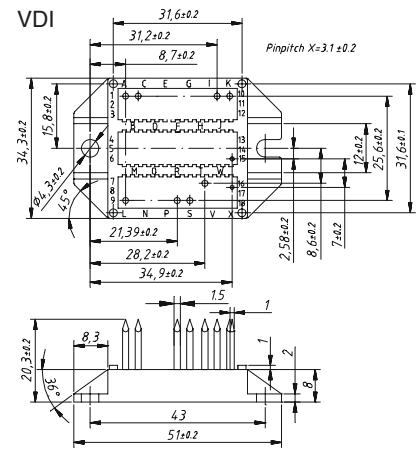
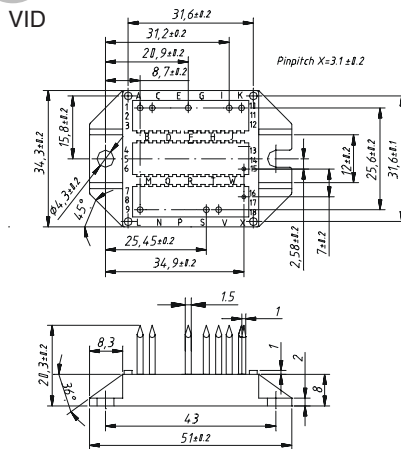
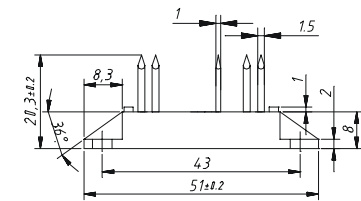
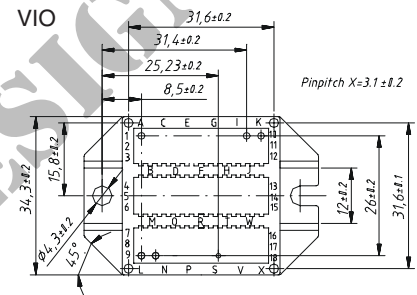
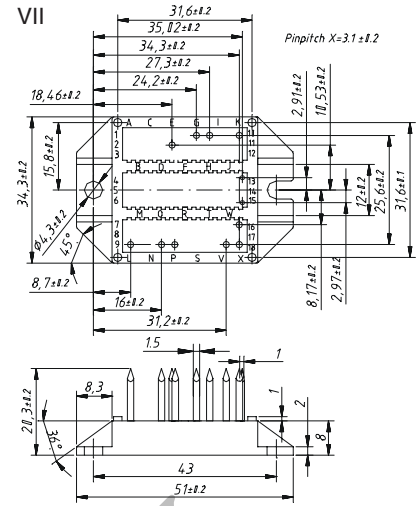
V_{ISOL}	$I_{ISOL} \leq 1\text{ mA}; 50/60\text{ Hz}$	3000	V~
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M_d	mounting torque (M4)	1.5 - 2.0	Nm lb.in.
a	Max. allowable acceleration	50	m/s^2

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.

d_S d_A	Creepage distance on surface (Pin to heatsink) Strike distance in air (Pin to heatsink)	11.2		mm mm
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Weight		24	g
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Data according to IEC 60747 and refer to a single transistor or diode unless otherwise stated.
IXYS reserves the right to change limits, test conditions and dimensions.

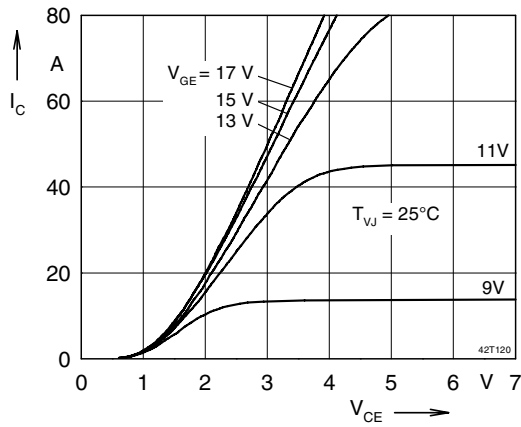


Fig. 1 Typ. output characteristics

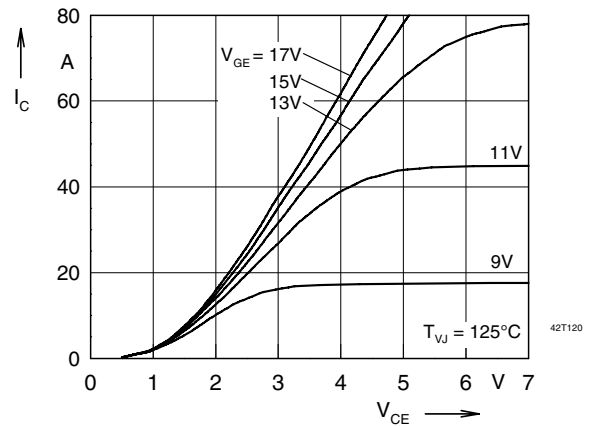


Fig. 2 Typ. output characteristics

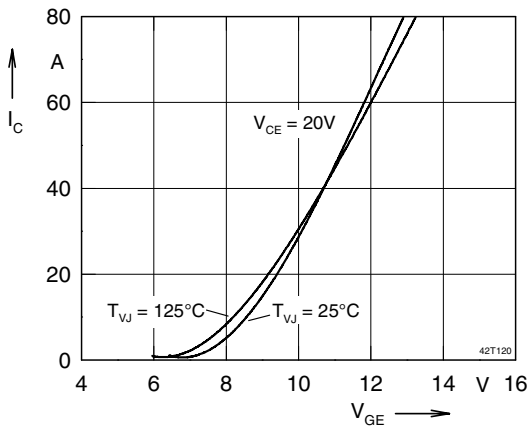


Fig. 3 Typ. transfer characteristics

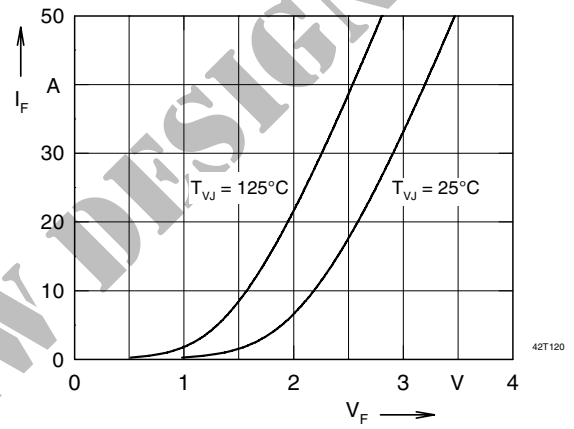


Fig. 4 Typ. forward characteristics of free wheeling diode

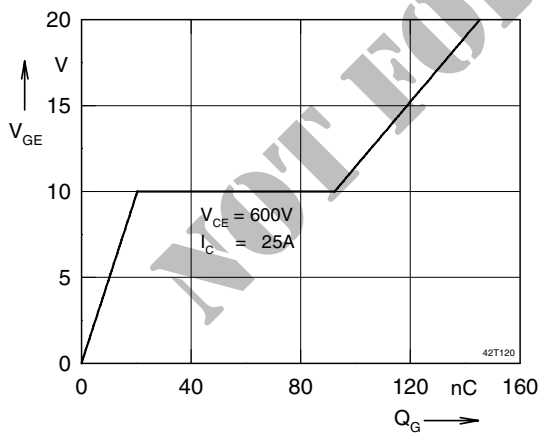


Fig. 5 Typ. turn on gate charge

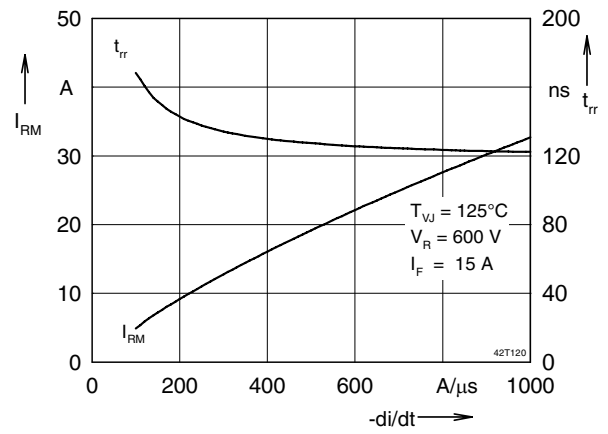


Fig. 6 Typ. turn off characteristics of free wheeling diode

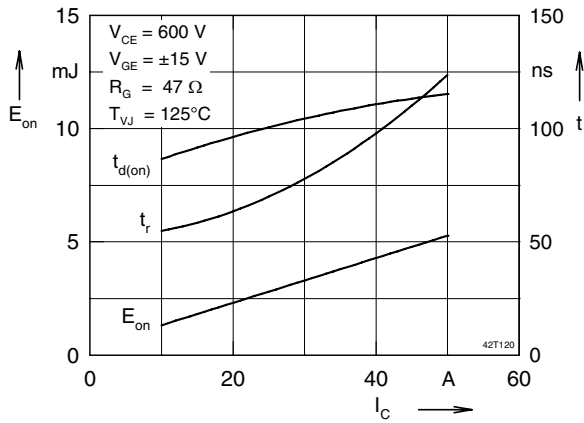


Fig. 7 Typ. turn on energy and switching

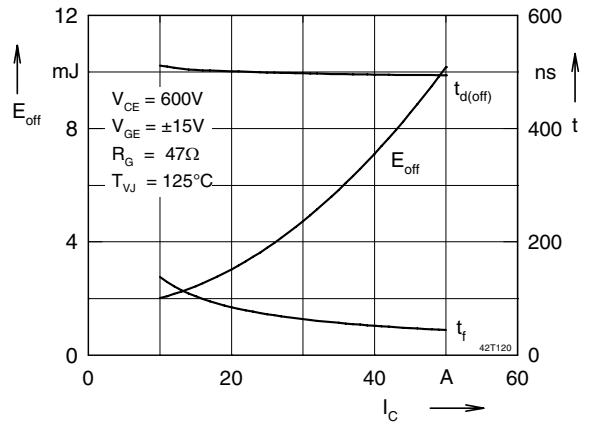


Fig. 8 Typ. turn off energy and switching times versus collector current

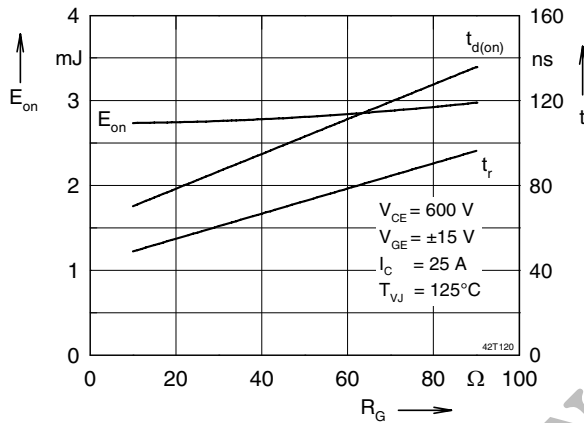


Fig. 9 Typ. turn on energy and switching

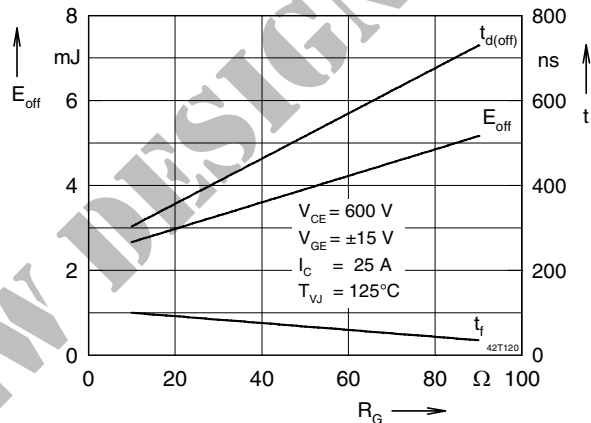


Fig. 10 Typ. turn off energy and switching times versus gate resistor

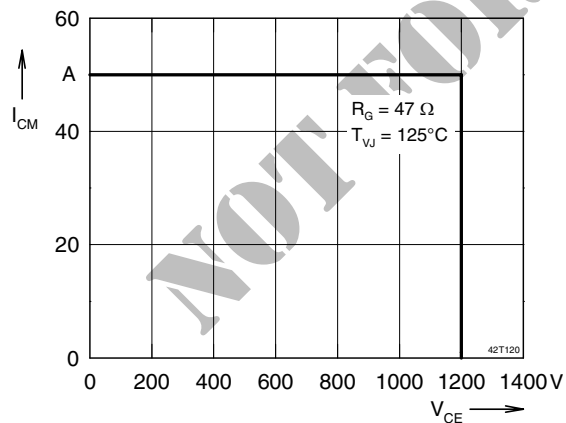


Fig. 11 Reverse biased safe operating area

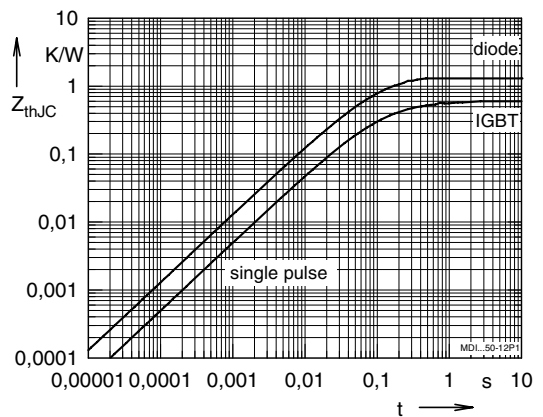


Fig. 12 Typ. transient thermal impedance RBSOA